

# UNITED STATES PATENT AND TRADEMARK OFFICE

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APPLICATION NO	NO PIEING DATE FIRST NAMED INVENTOR		ATTORNEY DOCKET NO CONFIRMATION NO		
09 937,363	01-17-2002	Christian Wunderlich	B-7062 7951		
75	90 05 19 2003				
Frank J Bonini Jr 86 The Commons At Valley Forge East 1288 Valley Forge Road PO Box 750 Valley Forge, PA 19482-0750		EXAMINER			
		EDMONDSON, LYNNE RENEE			
			ARTUMI	PAPER NUMBER	
			1725		
			DATE MAILED: 05/19/2003	3	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicatio	n No.		Applicant(s)	
		09/937,36	3		WUNDERLICH ET AL.	
Office Action Summary			Examiner			Art Unit
			Lynne Edr	monds	on	1725
Period fo	The MAILING DATE of this commun or Reply	ication	appears on the	cover	sheet with the	correspondence address
THE I - Exter after - If the - If NO - Failu - Any r	ORTENED STATUTORY PERIOD F MAILING DATE OF THIS COMMUNI nsions of time may be available under the provisions SIX (6) MONTHS from the mailing date of this comm period for reply specified above is less than thirty (3 period for reply is specified above, the maximum state to reply within the set or extended period for reply eply received by the Office later than three months a d palent term adjustment. See 37 CFR 1.704(b).	of 37 CF nunication 0) days, a atutory pe will, by st	DN. R 1.136(a). In no evel n. a reply within the statu eriod will apply and will tatute, cause the appli	nt, howe tory mini l expire S cation to	ever, may a reply be to imum of thirty (30) da SIX (6) MONTHS fro to become ABANDON	imely filed  ays will be considered timely.  m the mailing date of this communication.  IED (35 U.S.C. § 133).
1)[	Responsive to communication(s) fil	led on	<u>06 March 2003</u>			
2a)⊡	This action is <b>FINAL</b> .	2b)	This action is	non-fii	nal.	
3)	Since this application is in condition closed in accordance with the pract					
Dispositi	on of Claims					
4)⊡	Claim(s) 1-20 is/are pending in the	applica	ation.			
	4a) Of the above claim(s) is/a	re with	drawn from cor	sidera	ation.	
5) 🖸	Claim(s) <u>1-13 and 16-20</u> is/are allow	/ed.				
6) 🖸	Claim(s) <u>14 and 15</u> is/are rejected.					
7)	Claim(s) is/are objected to.					
	Claim(s) are subject to restrict	ction ar	nd/or election re	quirer	ment.	
	on Papers					
•	The specification is objected to by the					
10)[	The drawing(s) filed on is/are:	,	,	•	<u>*</u>	
445	Applicant may not request that any obj					
11) ☐ The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13)[•] Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) ⊠ All b) ☐ Some * c) ☐ None of:						
	1. Certified copies of the priority documents have been received.					
	2. Certified copies of the priority documents have been received in Application No					
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) ☐ The translation of the foreign language provisional application has been received.  15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment(s)						
1) Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (P nation Disclosure Statement(s) (PTO-1449) P.			5)		rry (PTO-413) Paper No(s) I Patent Application (PTO-152)

U.S. Patent and Trademark Office PTO-326 (Rev. 04-01) Application/Control Number: 09/937,363

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#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 1. Claims 14 and 15 are rejected under 35 U.S.C. 102(b) as being anticipated by Hayward (USPN 4720324).

Hayward teaches a process for producing a solderable surface and a functional surface on a dielectric substrate. The dielectric substrate is provided with copper structures (tracing), solderable surfaces are created by deposition of a Sn alloy by chemical reduction (electroless plating). A covering mask (resist) is placed over the solderable areas leaving functional areas (pads) exposed. Functional surfaces are created by chemical reduction (plating). After formation of pads and plated holes the masking material (resist) is removed (col 2 line 65 – col 3 line 10). The solderable material comprises gold, nickel, palladium or tin (col 5 lines 27-43). A solder mask is applied and functional areas are formed (col 5 line 35 col 6 line 20). Gold may be applied over the base layer of Ni (col 6 lines 44-46). The Sn layer may be removed

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before formation of the functional area by acid etching (col 5 lines 58-68). The covering mask may comprise a photo-resist which is applied and developed by exposure or may be screen-printed. A first mask (130) may be applied before forming the solderable areas with necessary areas left bare (exposed, col 4 line 38 – col 5 line 16). It is noted that the circuit carrier can be formed by any method. See also Hayward claims 1-3, 8-20 and 27-30.

2. Claims 14 and 15 are rejected under 35 U.S.C. 102(b) as being anticipated by Mack (USPN 4104111).

Mack teaches a process for producing a solderable surface and a functional surface on a dielectric substrate. The dielectric substrate is provided with copper structures (cladding), solderable surfaces are created by deposition of a Sn alloy by chemical reduction (electroless plating) (col 6 line 41 – col 7 line 12). A covering mask is placed over the solderable areas (col 7 lines 22-35) leaving functional areas (terminal pads) exposed (col 7 lines 29-35). Functional surfaces are created by chemical reduction (col 7 lines 36-66). After formation of pads and plated holes the masking material (resist) is removed (col 7 lines 56-62). Gold may be applied over the base layer which contains Ni (col 8 lines 8-26). The covering mask may comprise a photoresist which is applied and developed by exposure or may be screen printed (col 2 lines 1-14). A first mask (13) may be applied before forming the solderable areas with necessary areas left bare (exposed, col 6 lines 32-40). It is noted that the circuit carrier can be formed by any method. See also Mack claims 1-4, 9 and 10.

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3. Claims 14 and 15 are rejected under 35 U.S.C. 102(e) as being anticipated by Pommer et al. (USPN 6242078 B1).

Pommer teaches a process for producing a solderable surface (pad) and a functional surface (plated via) on a dielectric substrate (col 3 line 14-20). The dielectric substrate is provided with copper structures (layer, col 3 lines 13-20), solderable surfaces are created by deposition of a conductive metal (Ni, 54) onto the substrate (col 4 lines 1-19). A gold layer (56) is applied over the Ni layer (col 4 lines 43-53). Both pads and plated vias are formed by chemical reduction (electroless plating, col 4 lines 20-26 and lines 38-42). A covering mask (resist) is placed over the solderable areas leaving functional areas exposed (col 5 lines 1-12). Functional surfaces are created by chemical reduction (electroless plating) of a metal (col 5 lines 12-23). After formation of solderable areas and functional surfaces, the masking material (resist) is removed. A layer of metal (54) is removed by acid etching (col 5 lines 24-37). The covering mask may comprise a photo-resist which is applied and developed by exposure (col 5 lines 1-13). It is noted that the circuit carrier can be formed by any method. See also Pommer claims 1-8 and 16.

## Response to Arguments

4. Applicant's arguments regarding the process have been considered. It is noted that Hayward teaches the article and the article comprises the same structure regardless of the forming process.

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Therefore the 102 rejection of article claims 14 and 15 as anticipated by Hayward stand.

5. Applicant's arguments regarding the process have been considered. It is noted that Mack teaches the article and the article comprises the same structure regardless of the forming process.

Therefore the 102 rejection of article claims 14 and 15 as anticipated by Mack stand.

6. Applicant's arguments regarding the process have been considered. It is noted that Pommer teaches the article and the article comprises the same structure regardless of the forming process.

Therefore the 102 rejection of article claims 14 and 15 as anticipated by Pommer stand.

## Allowable Subject Matter

- 7. Claims 1-13 and 16-20 are allowed.
- 8. The following is an examiner's statement of reasons for allowance: The closest prior art teaches the invention essentially as claimed but teaches the mask covering the functional areas leaving solder regions exposed rather than covering solder regions and leaving functional areas exposed. See Hayward and Mack (USPN 4104111).

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Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

#### Conclusion

- 9. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Labzentis et al. (USPN 6383401 B1), Krokoszinski et al. (DE 3704547 A1, Au over Ni, photoresist, IDS), Kikuchi et al. (USPN 6278153 B1, Au over Ni, photoresist), Bengston et al. (USPN 5235139, Au over Ni or Co, photoresist, Sn), Etchells (USPN 5536908, photoresist, Sn), Sweitzer (USPN 5615477, photoresists, removal of metal, Ag, Au solderable and functional areas), Coppin (USPN 4487654), Gomes et al. (USPN 5250105), Kukansis et al. (USPN 5869126) and Larson (USPN 6044550).
- 10. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any

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extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

the advisory action. In no event, however, will the statutory period for reply expire later

than SIX MONTHS from the mailing date of this final action.

11. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Lynne Edmondson whose telephone number is (703)

306-5699. The examiner can normally be reached on M-F from 7-4 with alternate

Fridays off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Tom Dunn can be reached on (703) 308-3318. The fax phone numbers for

the organization where this application or proceeding is assigned are (703) 305-7718 for

regular communications and (703) 305-7115 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is (703) 308-

0651.

Lynne Edmondson

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Examiner

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LRE May 15, 2003

TOM DUNN

SUPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 1700